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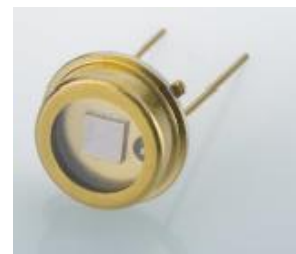
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EPD-365-0/2.5-3

- GaP photodiode
- 4.8 mm² active area
- 245 – 400 nm spectral range
- Low Dark Current
- High Spectral Sensitivity



Description

EPD-365-0-2.5-3 is a Schottky **GaP** photodiode with a large active area diameter of **4.8 mm²**, offering low dark current and excellent spectral sensitivity range from 245 to 400 nm. **EPD-365-0-2.5-3** comes in a **hermetically sealed TO-39 Package** with UG-11 filter and UV resistant glass window. It is widely used for medical engineering, measurements of UV-lamps, and for water purification facilities.

Miscellaneous Parameters (T_{CASE} = 25°C)

Parameter	Symbol	Value	Unit
Active Area	A	4.8	mm ²
Temperature Coefficient of I _b	T _C (I _b)	7.0	%/K
Acceptance Angle @ 50% S _λ	2φ	60	deg.
Operating Temperature	T _{OPR}	- 40 + 125	°C
Storage Temperature	T _{STG}	- 40 + 125	°C
Soldering Temperature (max. 5s)	T _{SOL}	max. 260	°C



Electro-Optical Characteristics (T_{CASE} = 25°C)

Parameter	Symbol	Condition				Unit
			min.	typ.	max.	
Spectral Range	λ	V _R =0V	245		400	nm
Peak Sensitivity	λ _P	V _R =0V		365		nm
Peak Responsivity	S _λ	V _R =0V, λ _P =365 nm	0.05	0.07		A/W
Spectral Bandwidth @ 50%	Δλ _{0.5}	V _R =0V		85		nm
Specific Detectivity	D	λ=365 nm		6.9x10 ¹²		$\frac{\text{cm}\cdot\sqrt{\text{Hz}}}{\text{W}}$
Dark Current	I _b	V _R =5 V		15	40	pA
Breakdown Voltage	V _B	I _R =10 μA	5			V
Shunt Resistance	S _{SH}	V _R =10 mV	80	100		GΩ
Noise Equivalent Power	NEP	λ=365 nm		3.2x10 ⁻¹⁴		$\frac{\text{W}}{\sqrt{\text{Hz}}}$
Junction Capacitance	C _J	V _R =0 V		1		nF
Switching Time	t _r / t _f	V _R =5 V, R _L =50 Ω		1 / 60		ns
Photo Current	I _P	V _R =0V, λ=365 nm, E _e =1 mW/cm ²		1.3		μA

